Approximate Storage in Solid-State Memories

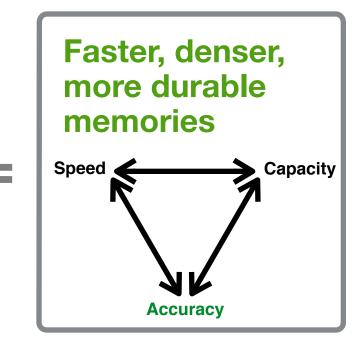
Phase-change memory (PCM)

- May scale beyond the limits of DRAM and flash.

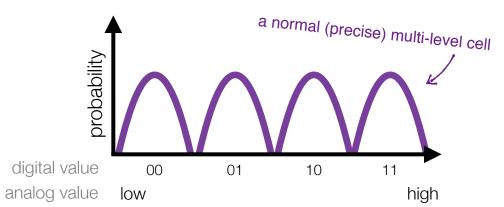
 Non-volatile.
- High-density MLC configurations can be slow.

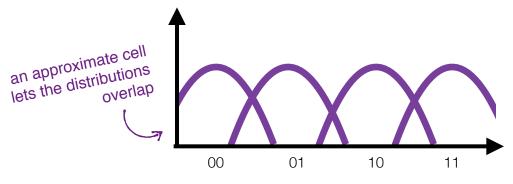
Cells wear out, limiting device lifetime.

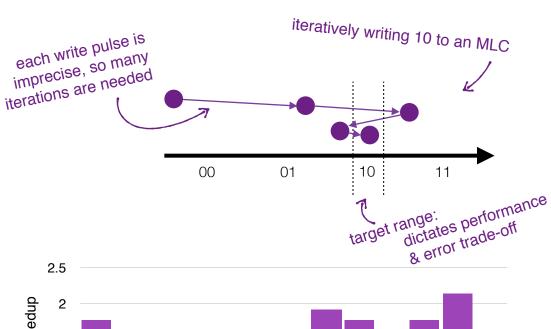
Approximate computing Much of the data in main memory and disk can tolerate occasional errors.

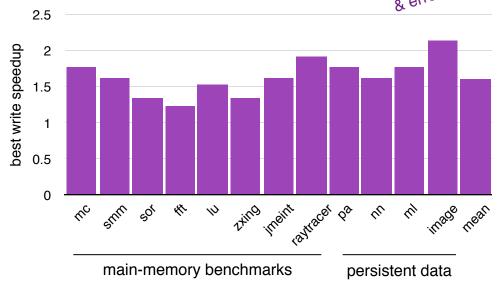


Accelerate writes to multi-level cells.

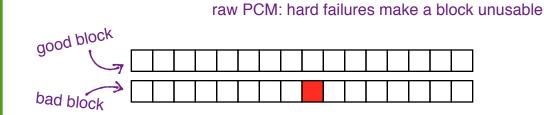


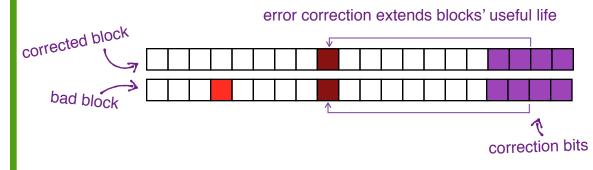




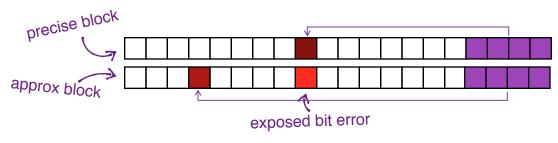


Extend lifetime by reusing failed blocks.





reuse blocks with uncorrectable failures for approximate data



(prioritizing the correction of higher-order bits)

